mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

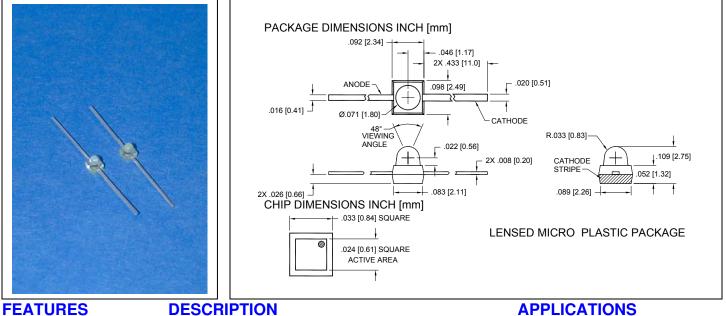
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Plastic Photodiode Packages with Leads

PDB-C144



- Micro package
- Photoconductive
- Low cost ٠
- High speed

The PDB-C144 is a blue enhanced PIN silicon photodiode in a photoconductive mode packaged in a water clear lensed micro plastic package.

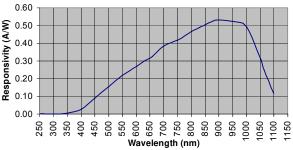
- · Smoke detectors
- Data links
- Scanners

ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		50	V
T _{STG}	Storage Temperature	-40	+100	°C
To	Operating Temperature	-40	+80	°C
Ts	Soldering Temperature*		+260	°C

* 1/16 inch from case for 3 seconds max.





ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
I _{SC}	Short Circuit Current	H = 100 fc, 2850 K	8	10		μΑ
I _D	Dark Current	V _R = 10 V		2	10	nA
R _{SH}	Shunt Resistance	V _R = 10 mV	100	500		ΜΩ
CJ	Junction Capacitance	$V_{R} = 10 V, f = 1 MHz$		25	30	pF
λ range	Spectral Application Range	Spot Scan	700		1100	nm
V_{BR}	Breakdown Voltage	I = 10 μA	30	100		V
NEP	Noise Equivalent Power	V _R = 10V @ λ = Peak		10x10 ⁻¹⁵		W/ $\sqrt{_{\rm Hz}}$
t _r	Response Time	RL = 1KΩ,V _R = 10 V		6	10	nS

**Response time of 10% to 90% is specified at 660nm wavelength light.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

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